

Green Products

20SQ045 SCHOTTKY BARRIER RECTIFIER

Applications:

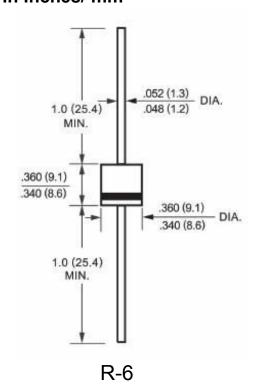
- DC-DC converters
- AC adapter
- High frequency rectification circuit
- Bypass diodes
- Photovoltaic Solar cell Protection Schottky Rectifier

Features:

- Super-high speed & low noise switching
- Low voltage drop
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



Mechanical Dimensions: In Inches/ mm



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Marking Diagram:



Where XXXXX is YYWWL

= Forward Current (20A)

S = Package Type Q = Device Type

045 = Reverse Voltage (45V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

| Device | Package | Shipping |
|---------|------------------|---------------|
| 20SQ045 | R-6 (Pb-Free) | 500pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Rating:

| Characteristics | Symbol Conditions | | Value | Unit |
|---------------------------------------|--------------------|-----------------------------|-------|------|
| Repetitive Peak Reverse Voltage | VRRM | - | 45 | V |
| Max. average forward current | I _{F(AV)} | R- load, Ta=25℃ | 20 | Α |
| Surge(Non-repetitive) Forward Current | I _{FSM} | 8.3ms single half sine-wave | 350 | Α |

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Electrical Characteristics (Ta=25℃ Unless otherwise specified)

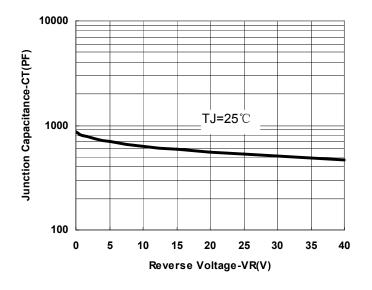
| Characteristics | Symbol | Conditions | | Max. | Unit |
|-----------------------------|--------|---------------------------|---------|------|------|
| Peak Forward Voltage | VFM | Iғм=20.0А,Та=25°С | | 0.55 | V |
| Peak Reverse Current | IRRM1 | VRM=VRRM | Ta=25℃ | 0.5 | mA |
| | IRRM2 | VRM-VRRM | Ta=100℃ | 50 | IIIA |
| Thermal Resistance(Typical) | R θJ-c | Between junction and case | | 3.0 | °C/W |
| | R θJ-L | Between junction and lead | | 2.0 | CIVV |

Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units | |
|--|------------------|---|---|-------|--|
| Max. Junction Temperature at reduced reverse voltage at reduced reverse voltage in DC forward mode | T _J | $V_{R}{\leqslant}80\%V_{RRM} \ V_{R}{\leqslant}50\%V_{RRM}$ | -55 to +150 -55 to +180 -55 to +200 | °C | |
| Max. Storage Temperature | T _{stg} | - | -55 to +150 | °C | |
| Approximate Weight | wt | - | 2.24 | g | |
| Case Style | R-6 | | | | |



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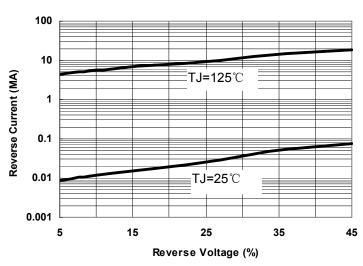


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

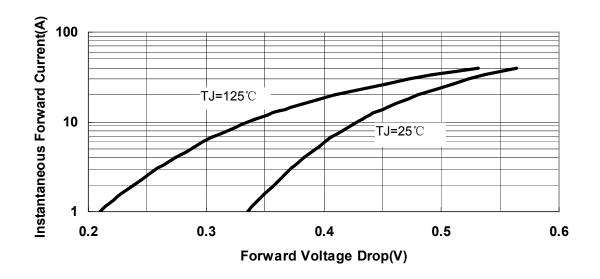


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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